

ESD7481MUT5G

Transient Voltage Suppressors

Micro-Packaged Diodes for ESD Protection

The ESD7481 is designed to protect voltage sensitive components that require ultra-low capacitance from ESD and transient voltage events. Excellent clamping capability, low capacitance, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its low capacitance, the part is well suited for use in high frequency designs such as USB 2.0 high speed and antenna line applications.

Features

- Ultra-Low Capacitance 0.25 pF
- Low Clamping Voltage
- Small Body Outline Dimensions: 0.60 mm x 0.30 mm
- Low Body Height: 0.3 mm
- Stand-off Voltage: 3.3 V
- Low Leakage
- Insertion Loss: 0.030 dBm
- Response Time is < 1 ns
- Low Dynamic Resistance < 1 Ω
- IEC61000-4-2 Level 4 ESD Protection
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- RF Signal ESD Protection
- RF Switching, PA, and Antenna ESD Protection
- Near Field Communications

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--|-----------------|----------------------|---------------------------|
| IEC 61000-4-2 (ESD) Contact Air | | ± 20 ± 20 | kV |
| Total Power Dissipation on FR-5 Board (Note 1) @ $T_A = 25^\circ\text{C}$ | P_D | 250 | mW |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 400 | $^\circ\text{C}/\text{W}$ |
| Junction and Storage Temperature Range | T_J, T_{stg} | -40 to +125 | $^\circ\text{C}$ |
| Lead Solder Temperature - Maximum (10 Second Duration) | T_L | 260 | $^\circ\text{C}$ |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

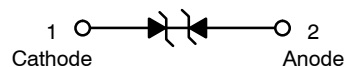
1. FR-5 = 1.0 x 0.75 x 0.62 in.

See Application Note AND8308/D for further description of survivability specs.



ON Semiconductor®

<http://onsemi.com>



X3DFN2
CASE 152AF

MARKING DIAGRAM

PIN 1

F M

F = Specific Device Code
M = Date Code

ORDERING INFORMATION

| Device | Package | Shipping† |
|--------------|---------------------|------------------------|
| ESD7481MUT5G | X3DFN2 (Pb-Free) | 15000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

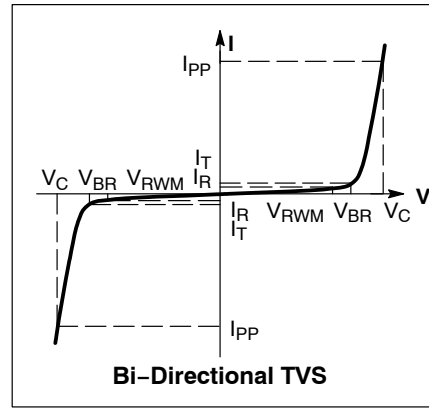
ESD7481MUT5G

ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter |
|-----------|---|
| I_{PP} | Maximum Reverse Peak Pulse Current |
| V_C | Clamping Voltage @ I_{PP} |
| V_{RWM} | Working Peak Reverse Voltage |
| I_R | Maximum Reverse Leakage Current @ V_{RWM} |
| V_{BR} | Breakdown Voltage @ I_T |
| I_T | Test Current |

*See Application Note AND8308/D for detailed explanations of datasheet parameters.



ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|----------------------------|-----------|--|---------------------|----------------|--------------|----------|
| Reverse Working Voltage | V_{RWM} | | | | 3.3 | V |
| Breakdown Voltage (Note 2) | V_{BR} | $I_T = 1\text{ mA}$ | | 6.0 | | V |
| Reverse Leakage Current | I_R | $V_{RWM} = 3.3\text{ V}$ | | < 1.0 | 50 | nA |
| Clamping Voltage (Note 3) | V_C | $I_{PP} = 1\text{ A}$ | | | 10 | V |
| Clamping Voltage (Note 3) | V_C | $I_{PP} = 3\text{ A}$ | | | 12 | V |
| ESD Clamping Voltage | V_C | Per IEC61000-4-2 | See Figures 1 and 2 | | | |
| Junction Capacitance | C_J | $V_R = 0\text{ V}, f = 1\text{ Mhz}$ $V_R = 0\text{ V}, f < 1\text{ GHz}$ | | 0.25 0.15 | 0.40 0.30 | pF |
| Dynamic Resistance | R_{DYN} | TLP Pulse | | 0.60 | | Ω |
| Insertion Loss | | $f = 1\text{ Mhz}$ $f = 8.5\text{ GHz}$ | | 0.030 0.234 | | dB |

- Breakdown voltage is tested from pin 1 to 2 and pin 2 to 1.
- Non-repetitive current pulse at $T_A = 25^\circ\text{C}$, per IEC61000-4-5 waveform.

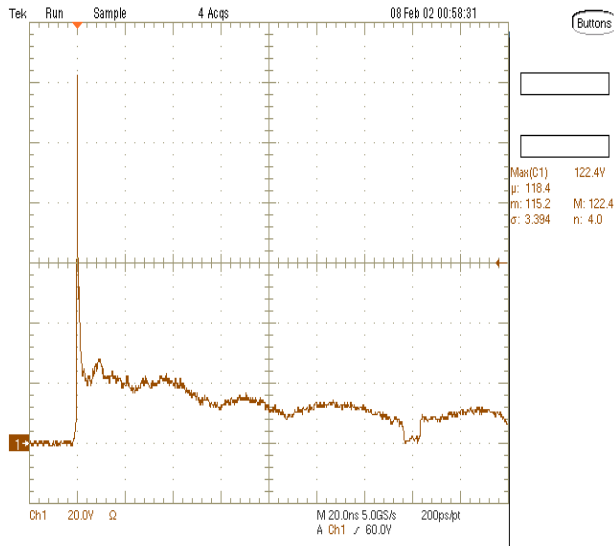


Figure 1. ESD Clamping Voltage Screenshot Positive 8 kV Contact per IEC61000-4-2

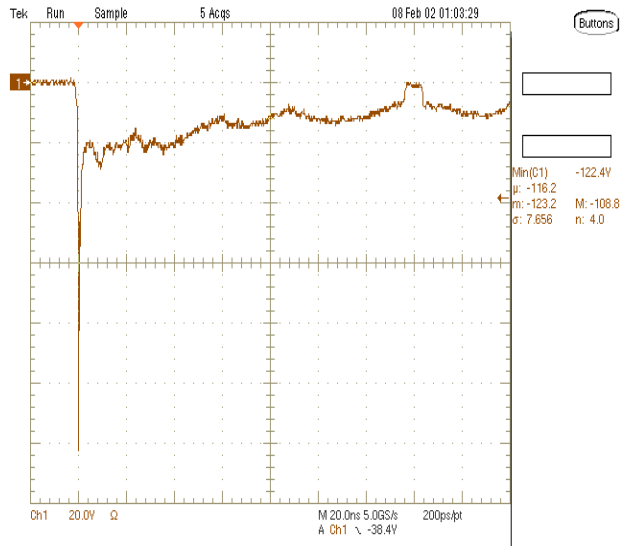


Figure 2. ESD Clamping Voltage Screenshot Negative 8 kV Contact per IEC61000-4-2

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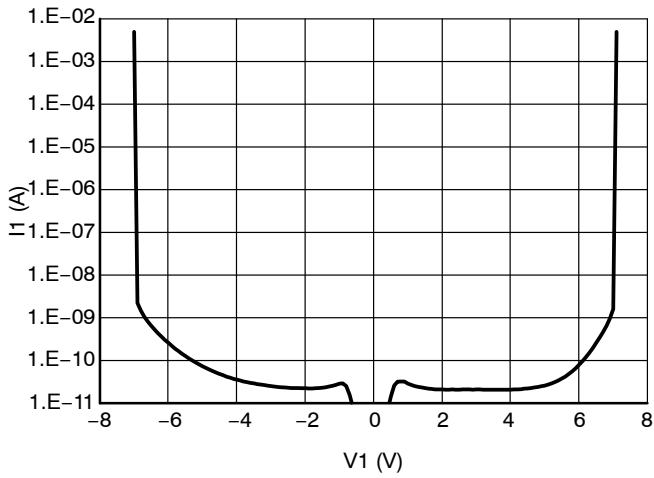


Figure 3. IV Characteristics

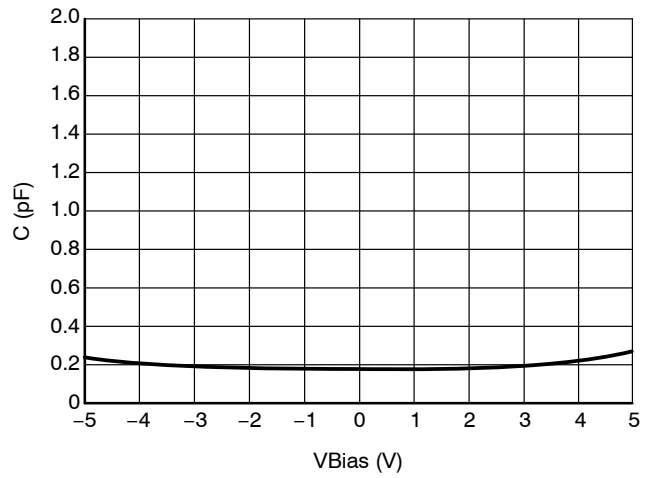


Figure 4. CV Characteristics

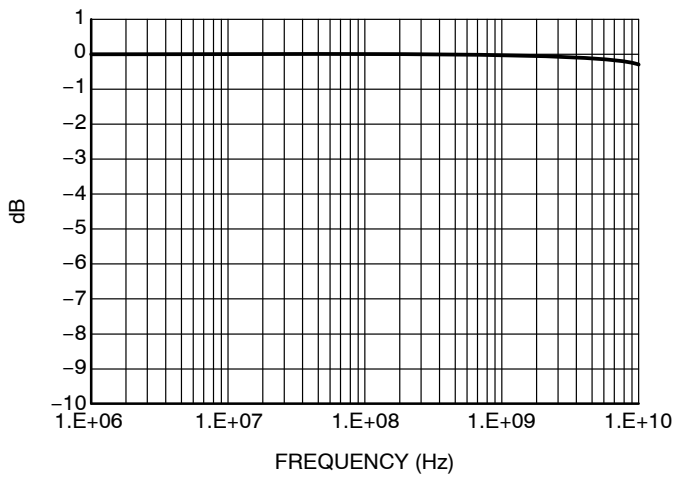


Figure 5. RF Insertion Loss

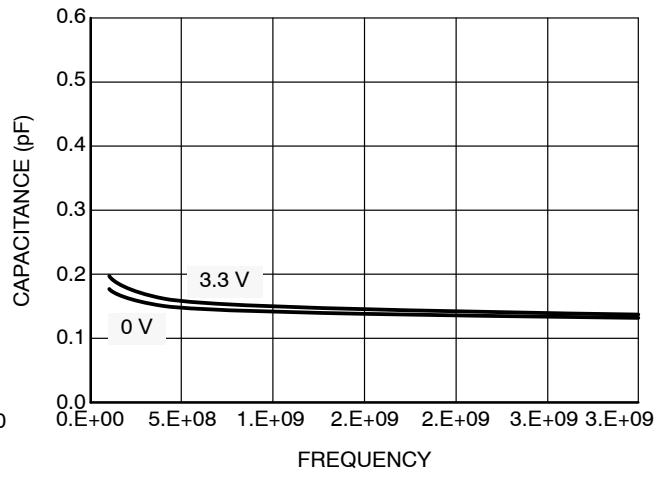


Figure 6. Capacitance over Frequency

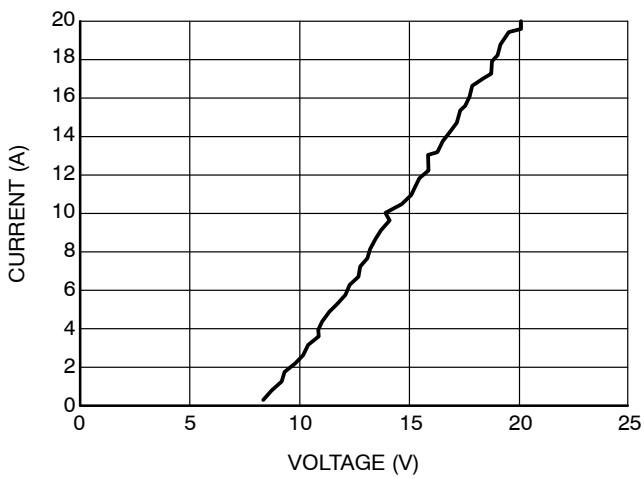


Figure 7. Positive TLP I-V Curve

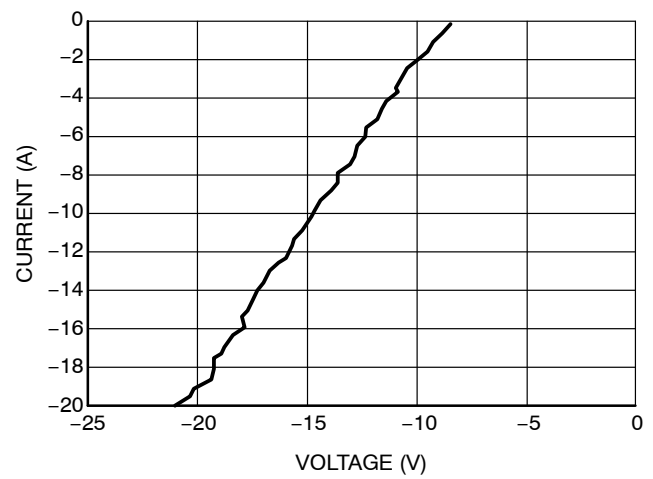


Figure 8. Negative TLP I-V Curve

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IEC 61000-4-2 Spec.

| Level | Test Voltage (kV) | First Peak Current (A) | Current at 30 ns (A) | Current at 60 ns (A) |
|-------|-------------------|------------------------|----------------------|----------------------|
| 1 | 2 | 7.5 | 4 | 2 |
| 2 | 4 | 15 | 8 | 4 |
| 3 | 6 | 22.5 | 12 | 6 |
| 4 | 8 | 30 | 16 | 8 |



Figure 9. IEC61000-4-2 Spec

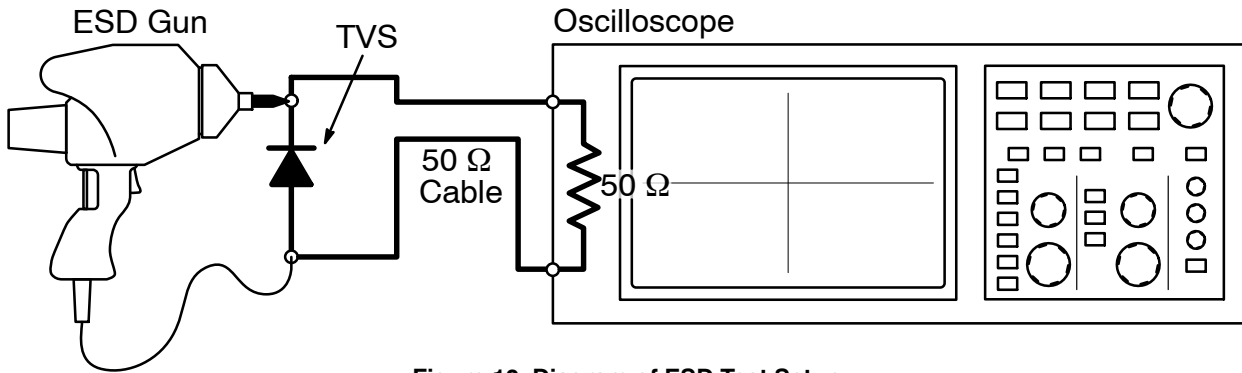


Figure 10. Diagram of ESD Test Setup

ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage

at the device level. ON Semiconductor has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how ON Semiconductor creates these screenshots and how to interpret them please refer to AND8307/D.

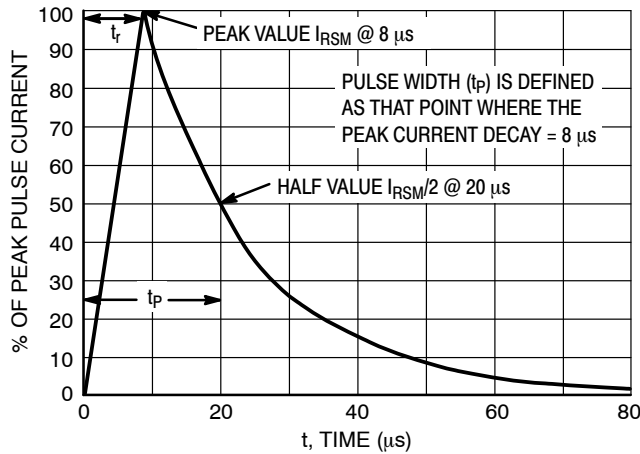
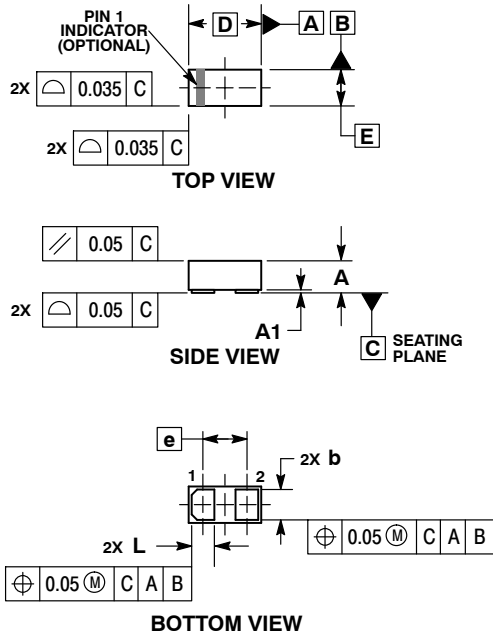


Figure 11. 8 X 20 μs Pulse Waveform

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PACKAGE DIMENSIONS

X3DFN2, 0.62x0.32, 0.355P, (0201)
CASE 152AF
ISSUE O

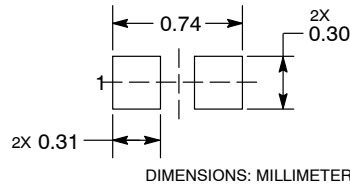


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.

| MILLIMETERS | | |
|-------------|-----------|------|
| DIM | MIN | MAX |
| A | 0.25 | 0.33 |
| A1 | --- | 0.05 |
| b | 0.22 | 0.28 |
| D | 0.62 BSC | |
| E | 0.32 BSC | |
| e | 0.355 BSC | |
| L | 0.17 | 0.23 |

RECOMMENDED MOUNTING FOOTPRINT*



See Application Note AND8398/D for more mounting details
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

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